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Shot-Noise-Driven Escape in Hysteretic Josephson Junctions

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We have measured the influence of shot noise on hysteretic Josephson junctions initially in the macroscopic quantum tunneling regime. The escape threshold current into the resistive state decreases monotonically with increasing average current through the scattering conductor, which is another tunnel junction. Escape is predominantly determined by excitation due to the wideband shot noise. This process is equivalent to thermal activation (TA) over the barrier at effective temperatures up to about 4 times the critical temperature of the superconductor. The presented TA model is in excellent agreement with the experimental results.

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Shot noise and full counting statistics (FCS) in mesoscopic conductors are currently intensively studied because such measurements yield fingerprints of conduction mechanisms of these scatterers [1–4]. Yet direct measurements of the second and higher moments of current or voltage are typically much more difficult and prone to errors as compared to the measurement of dc transport properties. This is because, in order to extract information about fluctuations, one generally needs to perform high frequency measurements on remotely connected samples at cryogenic temperatures, which is, in practice, a nontrivial task. Therefore, detectors of noise and FCS that operate directly on-chip near the noise source are of great importance. A recently proposed readout device of these fluctuations is a Josephson junction (JJ) threshold detector [5,6]. A mesoscopic nonhysteretic Josephson junction in the Coulomb blockade regime is another choice [7–9].

The dynamics of the JJ can be described as that of a phase (\(\varphi\)) particle in a tilted cosine potential; see Fig. 1. Under the influence of equilibrium environment fluctuations at low temperatures, the particle resides in the quantum mechanical ground state, from where the escape mechanism is tunneling [macroscopic quantum tunneling (MQT)] through the barrier. At higher temperatures, it assumes a nearly thermal population of the states, and the escape mechanism is predominantly thermal activation (TA) over the barrier top. Below we discuss the regime where excited states are not accessed by the influence of the thermal noise of the dissipative environment, which is an appropriate assumption based on our present measurements in the absence of shot noise and those of Ref. [10] in the same setup at low temperatures.

The influence of noisy current on escape characteristics is typically considered in two limits: (i) adiabatic (quasi-stationary) regime, where fluctuations of bias current that change the tilt of the cosine potential are so slow and weak that the phase particle remains in the ground state of the metastable well, and the escape rate is dictated by MQT from this varying ground state [6,11], or (ii) (nearly) resonance excitation limit, where most of the escape events are consequences of shot-noise-driven excitations of the phase particle into higher levels in the well. Because of the high frequency resonance character of our on-chip circuit, it turns out that the latter approach is more appropriate in describing the dynamics of the detector in this case.

In this Letter, we show that a hysteretic Josephson junction in the MQT regime can measure high frequency current fluctuations generated by a mesoscopic scatterer in nonequilibrium. We present a model in which the noisy current excites the phase particle in a metastable, nearly parabolic well out from the ground state, and, subsequently, the particle escapes from the well. This occurs via thermal activation at an equivalent temperature of the phase particle, which is determined by the competition between shot-noise excitation and relaxation due to the

![FIG. 1. (a) Measurement configuration. A split JJ in MQT regime measures the current fluctuations due to the shot noise of the scattering junction in the right arm. (b) Processes leading to escape from the zero-voltage (supercurrent) state into the resistive state. (c) Sketch of current pulses \(I_p\), with superimposed noise of \(I_{\text{shot}}\), and (d) the associated escape characteristics. The central quantities relating to the pulses and escape histograms have been indicated in the figure.](Image)

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dissipative environment. This model is in excellent agreement with our experimental results, and we are able to investigate Josephson phase dynamics up to effective temperatures which are about 4 times higher than the critical temperature of the superconductor. This is the effective temperature responsible for phase dynamics: The electrons and lattice of the superconductor remain, however, essentially at their base temperature.

Our measurement configuration with an electron micrograph of a split JJ detector is shown in Fig. 1. In a typical experiment, two currents \( I_N \) and \( I_p \) are injected into the circuit through large resistances (\( > 1 \) M\( \Omega \)) at room temperature. Current \( I_N \) is applied constantly, and it runs through another tunnel junction at a distance of 120 \( \mu m \) from the detector. This junction plays the role of the shot-noise source in the circuit. The dc component of this noise source and the circuit surrounding the JJ, at the threshold detector, in the limit of many levels in the well, as indicated by the combination of this environment and shot noise at the corresponding level separation, 

\[
\gamma_{j,j-1} = \frac{jFeI_N}{2\hbar\omega_{j,j-1}C}
\]

and

\[
\gamma_{j-1,j} = \frac{jFeI_N}{2\hbar\omega_{j,j-1}C} + \frac{i\omega_{j,j-1}}{\Omega}.
\]

The level dynamics described by Eqs. (1) and (2) can be described by the equivalent temperature \( T^* \) and effective quality factor \( Q^* \) by requesting \( \gamma_{j,j-1} = j(\omega_{j,j-1}/2Q^*) \times [\coth(\hbar\omega_{j,j-1}/2kB_T^*) - 1] \) and \( \gamma_{j-1,j} = j(\omega_{j,j-1}/2Q^*) \times [\coth(\hbar\omega_{j,j-1}/2kB_T^*) + 1] \). This yields \( Q^* = Q \) and, with \( \omega_{j,j-1} = \omega_p \),

\[
k_B T^* \approx \frac{\hbar\omega_p}{2\arctan(1 + QFeI_N/\hbar\omega_p^2C)}.
\]

In the following, we make use of standard results of the influence of temperature on the decay from a cubic metastable well (see, e.g., Ref. [14]) and note that, formally, we do not need to make a distinction of whether the temperature is determined by the equilibrium environment \( T \) or by the combination of this environment and shot noise \( T^* \). We can infer that (classical) thermal activation is the dominant escape mechanism, provided \( T^* > T_0 = \hbar\omega_p/2\pi k_B \). This yields a condition for the validity of the TA model: \( \arctan(1 + QFeI_N/\hbar\omega_p^2C)/\pi < 1 \). This is fulfilled at all currents \( I_N \) that were employed in the experiments, as we will show below. With this procedure, it is then straightforward to obtain the switching probability of the threshold detector, in the limit of many levels in the well, as \( P(I_p) = 1 - \exp(-\Gamma\Delta t) \). Here \( \Gamma = (\omega_c/2\pi) \times \exp(-\Delta U/k_B T^*) \) is the standard TA escape rate, \( \Delta t \) is
the length of the current pulse, and \( \Delta U = 4\sqrt{2}E_J(1 - I_p/I_c)^{3/2}/3 \) is the height of the potential barrier at the particular bias point \( I_p \). The expressions above allow us to evaluate the position \( I_{0.5} \) and the width \( \Delta I = I_{0.9} - I_{0.1} \) of the escape threshold, where \( I_c \) is defined by \( P(I_c) = x \); see Fig. 1(d). These approximate results were compared to those obtained by full level dynamics calculation (LDC) [15] numerically. The overall agreement between the two results is good, although \( I_{0.5} \) from the two methods can deviate by a few percent depending on how one obtains the level positions and widths near the top of the barrier in LDC.

In the limit of large noise currents, \( \tilde{I}_N \gg \hbar \omega_p C/(QF) \), we obtain \( T^* \approx QF \tilde{I}_N/(2k_B \omega_p C) \), which can be written in a more familiar looking form \( T^* \approx F \tilde{I}_N/(2k_B/R) \). This is a valid approximation in a wide range of experimental parameters. The expressions of TA escape and the current dependence of the barrier height combined with this approximate expression of \( T^* \) finally allow us to approximate \( I_{0.5} \) as

\[
I_{0.5}/I_c \approx 1 - \left( \frac{3}{4\sqrt{2}} \right)^{2/3} \left[ \ln \left( \frac{\omega_p \Delta t}{2\pi \kappa_{0.5}} \right) \right]^{2/3} \left( QF \frac{E_C}{E_J} \frac{\tilde{I}_N}{\omega_p} \right)^{2/3}
\]

and \( \Delta I \), assuming \( \omega_p \Delta t \gg 1 \), as

\[
\Delta I/I_c \approx \left[ \ln(\kappa_{0.9}) - \ln(\kappa_{0.1}) \right] \left( QF \frac{E_C}{E_J} \frac{\tilde{I}_N}{\omega_p} \right)^{2/3}.
\]

Here \( \kappa_{0.5} = -\ln(1 - \lambda) \).

We report on data of two samples, A and B, which were fabricated by standard electron beam lithography and shadow evaporation with aluminum as the superconductor. The samples were measured via adequately filtered signal lines in dilution refrigerators at bath temperatures of 30 mK—1 K. Sample A had a split JJ detector and one scattering junction as in the scheme of Fig. 1. Sample B had a single JJ as a detector, and it had two scattering junctions located symmetrically with respect to the detector (at a distance of 120 \( \mu \)m) and with respect to two long injection lines. In this sample, the two scattering junctions were made intentionally very different to check the invariance of the results with respect to junction properties. The parameters of the two samples are listed in Table I.

Data in Fig. 2(a) show results of a control experiment on sample B at the base temperature \( T \approx 30 \) mK, where the trapezoidal pulse current \( I \) was injected through (i) one of the long injection lines, (ii) through scatterer 1, and (iii) through scatterer 2. The histogram of case (i) lies at higher currents than those of (ii) and (iii), which in turn practically overlap with each other. This demonstrates that shot noise tends to push the threshold towards lower values of current, as predicted, e.g., by Eq. (4). Furthermore, these data demonstrate that the noise is predominantly, and equally in (ii) and (iii), generated by the scattering tunnel junctions. The calculated lines run through the corresponding experimental histograms assuming MQT without any noise in (i) and TA with \( T^* \) evaluated from Eq. (3) with \( QF = 5 \) in (ii) and (iii). The latter value is realistic in terms of the expected \( Q \approx 10 \) [10] and \( F \leq 1 \).

Figure 2(b) shows data on sample B at \( T = 40 \) mK. The threshold current \( I_{0.5} \), i.e., the pulse current at which the switching probability is 50%, has been plotted as a function of \( \tilde{I}_N \) through scatterer 2. The data, shown by solid symbols, follow the prediction of the model presented above, again with \( QF = 5 \). The initial plateau in the experimental data below \( I_{0.5} \approx 100 \) nA arises because the scattering junction is not in the linear quasiparticle tunneling regime here. The inset in Fig. 2(b) shows the IV curve of this junction. In Fig. 2(c) we plot, in addition to similar data as in Fig. 2(b), the equivalent temperature \( T^* \) in the measurement of sample A when current \( \tilde{I}_N \) is varied between 2 and 8 \( \mu \)A. There are two interesting points to note: (i) We are able to study Josephson dynamics of the JJ up to \( T^* \approx 5 \) K, about 4 times above the critical temperature \( T_C \)

![FIG. 2. Histogram positions under shot-noise injection.](image)

(a) Escape histograms of sample B when current pulses have been injected through the long injection line (open circles) and through the two noise sources (source 1, squares; source 2, solid circles), respectively. The lines are the corresponding theoretical results. (b) Experimental results (circles) on the switching threshold current \( I_{0.5} \) against the average current \( \tilde{I}_N \) through scatterer 2 in sample B. The solid line is again the result of the used theoretical model. The inset shows the IV curve of the noise source. (c) Similar data as in (b) but for sample A. The rising curve shows the equivalent temperature \( T^* \), which ranges from 2 to 5 K. Pulse length was \( \Delta t = 800 \) \( \mu \)s.
of aluminum. (ii) At all currents employed, we are well above the threshold \( T_0 \approx 0.3 \ \text{K} \) of thermal activation.

Figure 3(a) shows the width of the switching threshold, \( \Delta I_s \), of sample A. Again, the experimental (circles) and theoretical (line) results are in good agreement between each other using the same fit parameters as in Fig. 2. In Fig. 3(b), data on switching of sample A has been plotted in two different experimental conditions, in each case as \( \Delta I_s \) vs \( I_{0.5} \). The open circles are data where the bath temperature has been varied by heating the sample stage to several temperatures \( T \) in the range 0.03—1 K. The solid circles are data taken at the base temperature \( T \approx 30 \ \text{mK} \) but varying the equivalent temperature \( T' \), injecting different levels of \( I_N \). The line closely following the latter data is from the thermal activation model. At first sight, it is surprising that the truly thermal data (open circles) fall far below this line and the other set of data. This is, however, accounted for by the fact that, when increasing the bath temperature close to \( T_C \) of aluminum (\( \sim 1.2 \ \text{K} \)), the BCS energy gap is progressively diminishing, thus leading to decrease of the critical current. The line following closely this data set is obtained by using the very same thermal activation model but by taking into account suppression of the BCS gap due to temperature \( T \) [16]. This figure thus demonstrates that our thermal activation model is in good agreement with the shot-noise data and that it is indeed possible, by promoting shot noise, to study Josephson dynamics at effective noise temperatures higher than \( T_C \) without suppressing superconductivity.

Finally, there are a few more topics to address. We found out that the adiabatic models of rocking slowly the current bias of the JJ do not account for our observations on shot noise: The adiabatic models, involving no excitations, predict exponential dependence in variance of the current of the tunneling rate from the ground state [6,11]. Our experimental results demonstrate, however, much weaker dependence, which we derived in this Letter. The (nearly) resonant model works in this case because the high frequency shot noise can pass the detector junction. Furthermore, we expect that the low frequency noise (\( \ll 1 \ \text{GHz} \)) does not run through the detector junction because of the high-pass character of the setup. Note that at dc we suppress the detector current due to \( I_N \) totally. The second issue is the assessment of a MQT detector as an absolute noise detector. Based on the invariance of the obtained results, especially in terms of results on different scatterers on the same sample [see Fig. 2(a)], we suggest that this kind of a detector could be made into an absolute on-chip detector of Fano factors [1], and noise in general, by careful tailoring of the circuit surrounding the JJ and by measuring \( Q \) independently.

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[12] Our junctions are biased at high enough \( I/I_C \) and their \( I_C \) is sufficiently large such that we can discuss the escape dynamics as if only one well exists [10].